NSN 5961-01-418-2455

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-418-2455 **Inclosure Material:** Metal **Overall Length:** 35.5 millimeters **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-203ab **Electrode Internally-electrically Connected To Case:** Cathode **Mounting Method:** Threaded stud **Semiconductor Material:** Selenium Voltage Rating In Volts Per Characteristic: 1200.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 120.00 amperes forward current, average of standard range **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 1 threaded stud and 1 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: